



## -30V/-20A P-Channel Junction Power MOSFET

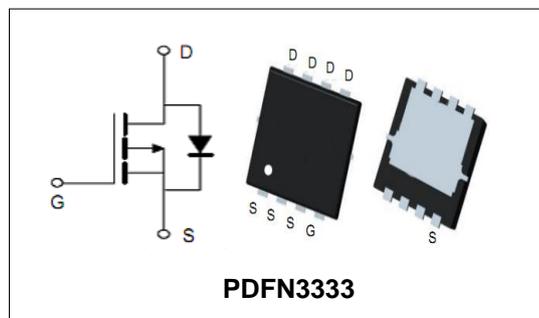
### Features

- New technology for high voltage device.
- Low on-resistance and low conduction losses
- Ultra Low Gate Charge cause lower driving requirements

BVDSS	-30	V
ID	-20	A
RDSON@VGS=-10V	18	mΩ
RDSON@VGS=-4.5V	25	mΩ

### Applications

- High Side Load Switch
- Battery Switch
- Optimized for Power Management Applications for Portable Products, such as Aeromodelling, Power bank, Brushless motor, Main board , and Others



### Order Information

Product	Package	Marking	Reel Size	Reel	Carton
PTQ20P03	PDFN3333	PTQ20P03	13inch	5000PCS	50000PCS

### Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit	
<b>Common Ratings (TC=25°C Unless Otherwise Noted)</b>				
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	-30	V	
$V_{GS}$	Gate-Source Voltage	±20	V	
$T_J$	Maximum Junction Temperature	150	°C	
$T_{STG}$	Storage Temperature Range	-55 to 150	°C	
$I_S$	Diode Continuous Forward Current	TC =25°C	-20	A
<b>Mounted on Large Heat Sink</b>				
$I_{DM}$	Pulse Drain Current Tested (Silicon Limit) (Note1)	TC =25°C	-60	A
$I_D$	Continuous Drain current	TC =25°C	-20	A
$P_D$	Maximum Power Dissipation	TA =25°C	2.5	W
$R_{\theta Ja}$	Thermal Resistance Junction-to-Ambient (Note2)		50	°C/W

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Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
<b>Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
V <sub>(BR)DSS</sub>	Drain- Source Breakdown Voltage	VGS=0V ID=-250μA	-30	--	--	V
I <sub>DSS</sub>	Zero Gate Voltage Drain current	VDS=-24V,VGS=0V	--	--	-1	μA
I <sub>GSS</sub>	Gate-Body Leakage Current	VGS=±20V,VDS=0V	--	--	±100	nA
V <sub>GS(TH)</sub>	Gate Threshold Voltage	VDS=VGS,ID=-250μA	-1	-1.4	-3	V
R <sub>DS(ON)</sub>	Drain-Source On-State Resistance (Note3)	VGS=-10V, ID=-10.5A	--	18	22	mΩ
		VGS=-4.5V, ID=-6A	--	25	33	
<b>Dynamic Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated) (Note4)</b>						
C <sub>iss</sub>	Input Capacitance	VDS=-15V, VGS=0V, F=1MHz	--	1500	--	pF
C <sub>oss</sub>	Output Capacitance		--	327	--	pF
C <sub>rss</sub>	Reverse Transfer Capacitance		--	276	--	pF
Q <sub>g</sub>	Total Gate Charge	VDS=-15V, ID=-9.1A, VGS=10V	--	30	--	nC
Q <sub>gs</sub>	Gate-Source Charge		--	5.3	--	nC
Q <sub>gd</sub>	Gate-Drain Charge		--	7.52	--	nC
<b>Switching Characteristics (Note4)</b>						
t <sub>d(on)</sub>	Turn-on Delay Time	VDD=-15V, ID=-1A, VGEN=-10V RG=6Ω	--	14	--	nS
t <sub>r</sub>	Turn-on Rise Time		--	16	--	nS
t <sub>d(off)</sub>	Turn-off Delay Time		--	95	--	nS
t <sub>f</sub>	Turn-off Fall Time		--	65	--	nS
<b>Source- Drain Diode Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
V <sub>SD</sub>	Forward on voltage	IS=-10A,VGS=0V	--	--	-1.2	V

Note:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board, t ≤ 10 sec.
3. Pulse Test: pulse width ≤ 300 us, duty cycle ≤ 2%.
4. Guaranteed by design, not subject to production testing.



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Typical Characteristics

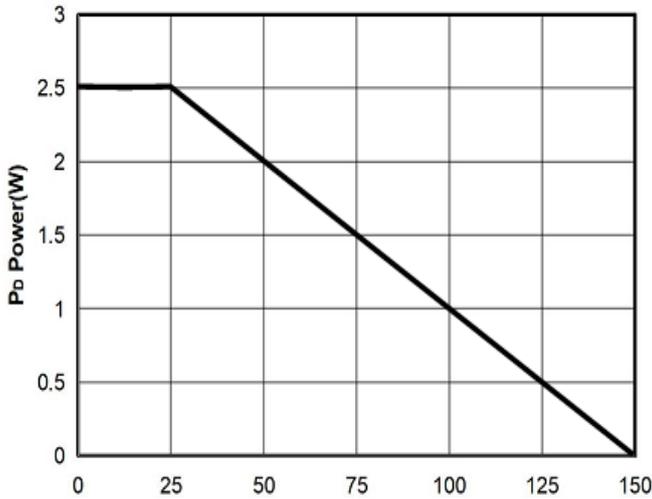


Figure1: Tj Junction Temperature (°C)

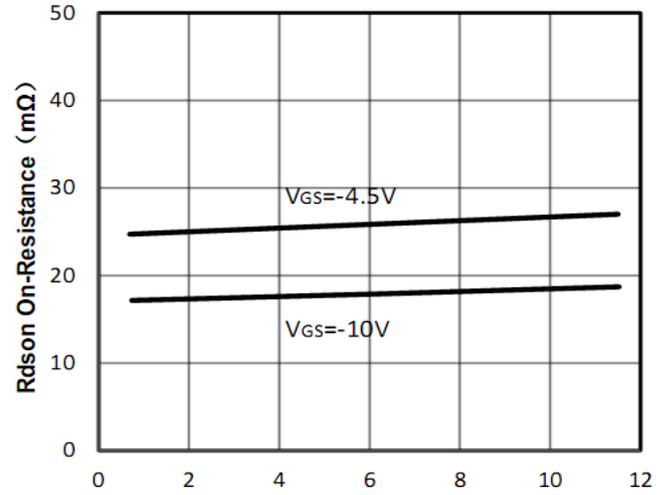


Figure2: -Id Drain Current (A)

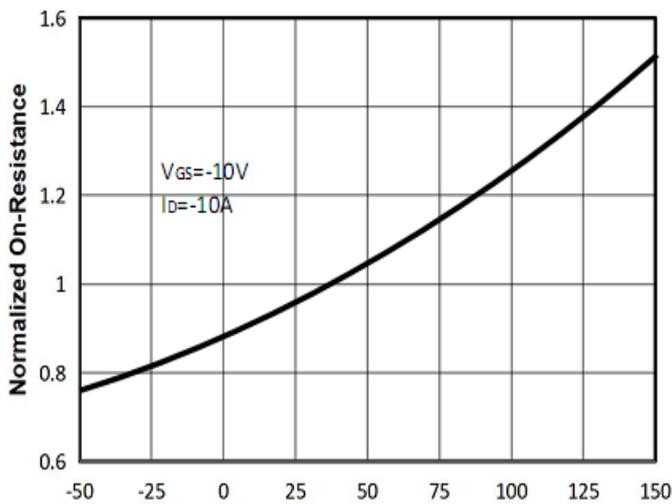


Figure3: Tj Junction Temperature (°C)

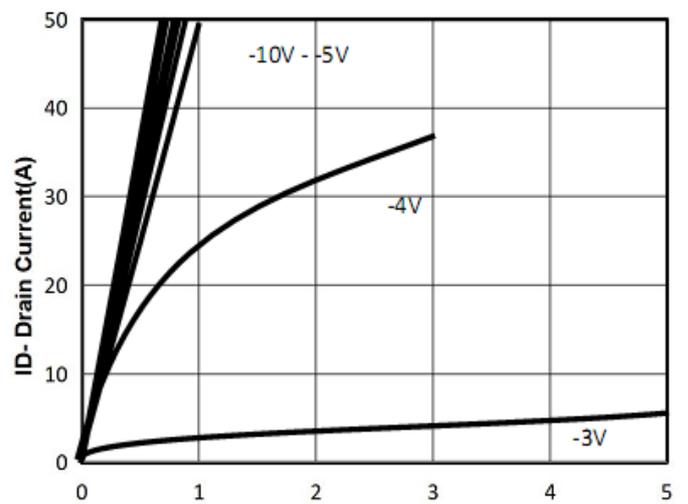


Figure4: -Vds Drain-Source Voltage (V)

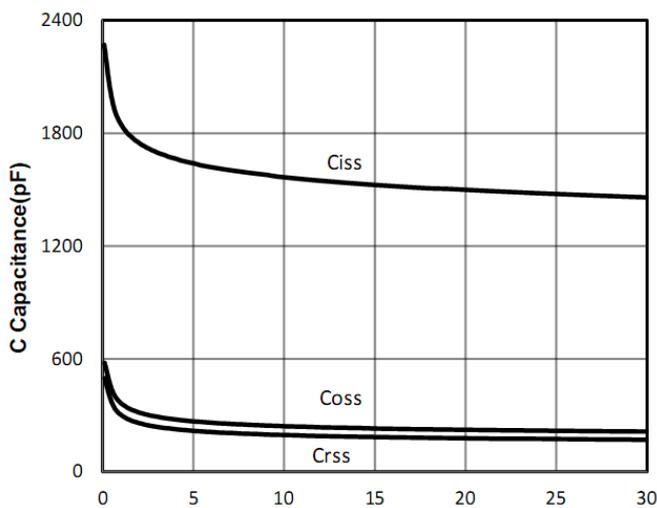


Figure5: -Vds Drain-Source Voltage (V)

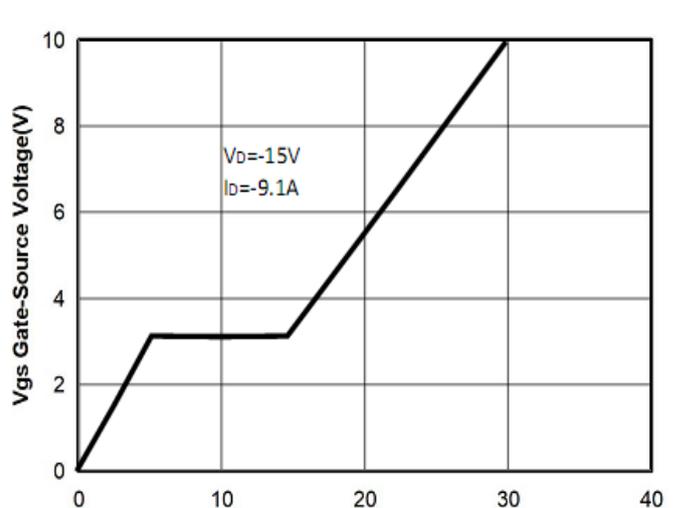


Figure6: Qg Gate Charge (nC)



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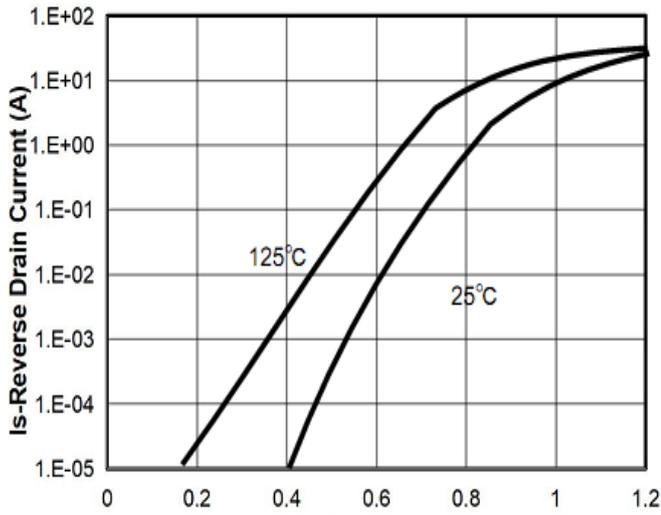


Figure7: -Vsd Source-Drain Voltage (V)

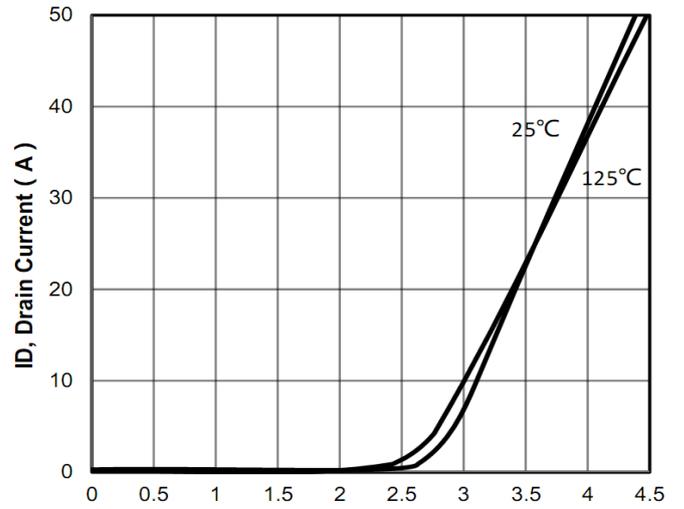


Figure8: -Vgs Gate-Source Voltage (V)

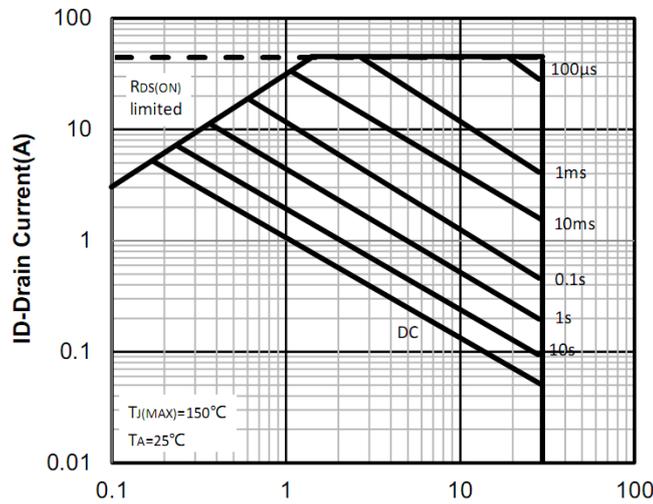


Figure9: -VDS Drain-Source Voltage (V)

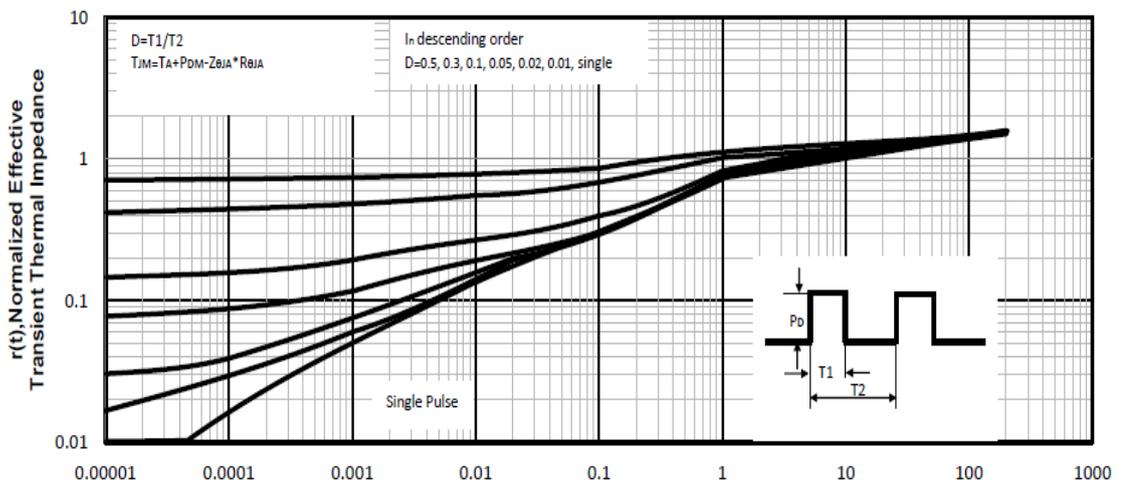


Figure10: Square Wave Pulse Duration (sec)

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Test Circuit and Waveform:

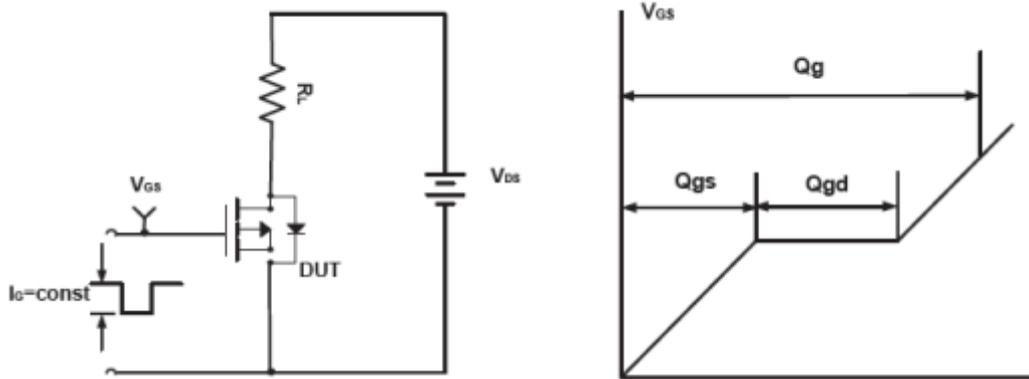


Figure A Gate Charge Test Circuit & Waveforms

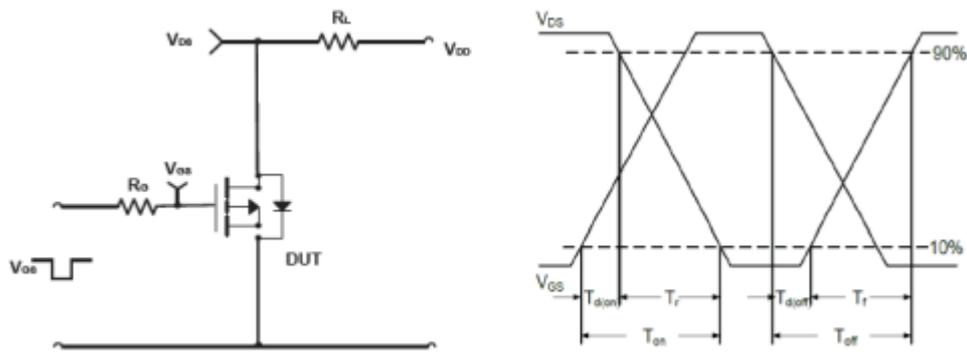


Figure B Switching Test Circuit & Waveforms

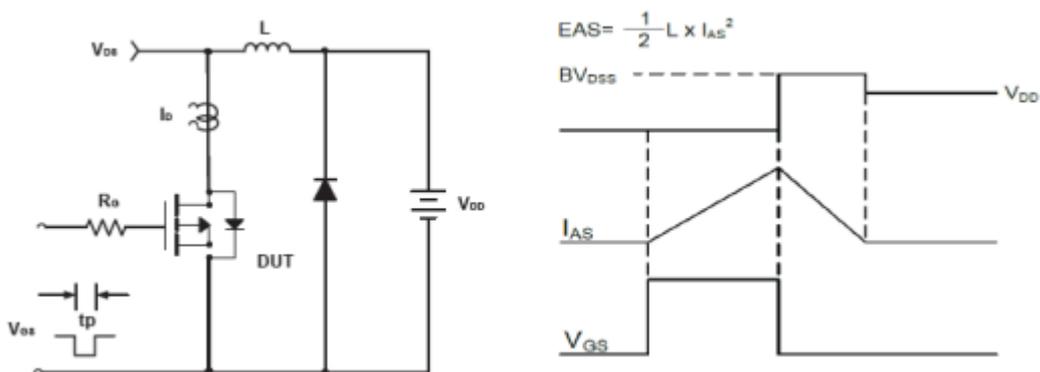
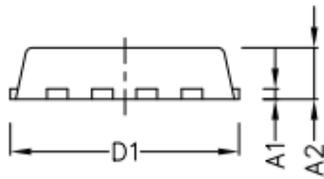


Figure C Unclamped Inductive Switching Circuit & Waveforms

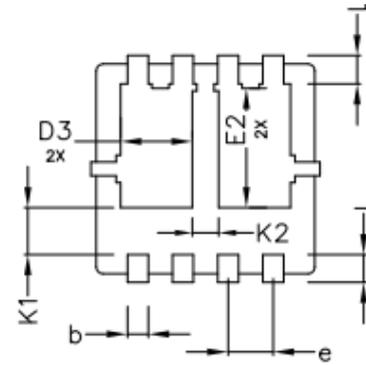


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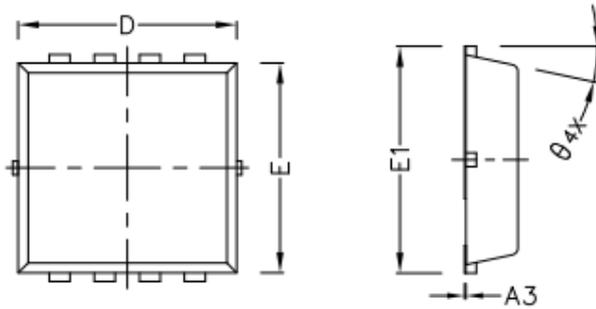
PDFN3333 Package Outline Dimensions (Units: mm)



SIDE VIEW

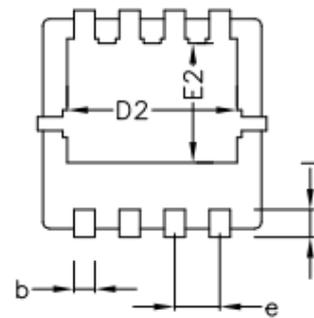


BOTTOM VIEW  
OPTION 2



TOP VIEW

SIDE VIEW



BOTTOM VIEW  
OPTION 1

COMMON DIMENSIONS (UNITS OF MEASURE IS mm)			
	MIN	NORMAL	MAX
A1	0.152 BSC		
A2	0.650	0.750	0.850
A3	0.005	-	0.020
b	0.250	0.300	0.350
D	3.050	3.150	3.250
D1	3.200	3.300	3.400
D2	2.350	2.450	2.550
D3	0.935	1.035	1.135
E1	3.150	3.300	3.450
E	2.950	3.050	3.150
E2	1.635	1.735	1.835
e	0.650 TYPE		
L	0.300	0.400	0.500
θ	12° TYPE		
K1	0.680 REF		
K2	0.380 REF		
L1	0.410 REF		